

# MBR6045WT

## SWITCHMODE™ Power Rectifier

The SWITCHMODE power rectifier employs the use of the Schottky Barrier principle with a Platinum barrier metal.

### Features

- Dual Diode Construction; Terminals 1 and 3 May Be Connected for Parallel Operation at Full Rating
- 45 V Blocking Voltage
- Low Forward Voltage Drop
- Guard-ring for Stress Protection and High dv/dt Capability (> 10 V/ns)
- 175°C Operating Junction Temperature
- Pb-Free Package is Available\*

### Mechanical Characteristics

- Case: Epoxy, Molded
- Weight: 4.3 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds

### MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Peak Repetitive Reverse Voltage	$V_{RRM}$	45	V
Working Peak Reverse Voltage	$V_{RWM}$		
DC Blocking Voltage	$V_R$		
Average Rectified Forward Current (Rated $V_R$ , $T_C = 125^\circ\text{C}$ )	$I_{F(AV)}$	30 60	A
	Per Diode Per Device		
Peak Repetitive Forward Current, (Rated $V_R$ , Square Wave, 20 kHz, $T_C = 90^\circ\text{C}$ )	$I_{FRM}$	60	A
	Per Diode		
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	$I_{FSM}$	500	A
Peak Repetitive Reverse Current (2.0 $\mu\text{s}$ , 1.0 kHz)	$I_{RRM}$	2.0	A
Storage Temperature Range	$T_{stg}$	-65 to +175	°C
Operating Junction Temperature (Note 1)	$T_J$	-65 to +175	°C
Peak Surge Junction Temperature (Forward Current Applied)	$T_{J(pk)}$	175	°C
Voltage Rate of Change	dv/dt	10,000	V/ $\mu\text{s}$

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. The heat generated must be less than the thermal conductivity from Junction-to-Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ .

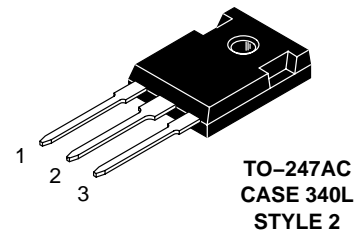
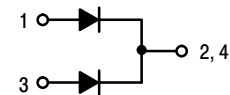
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



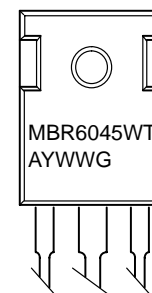
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## SCHOTTKY BARRIER RECTIFIER 60 AMPERES, 45 VOLTS



### MARKING DIAGRAM



A = Assembly Location  
Y = Year  
WW = Work Week  
G = Pb-Free Package

### ORDERING INFORMATION

Device	Package	Shipping
MBR6045WT	TO-247	30 Units/Rail
MBR6045WTG	TO-247 (Pb-Free)	30 Units/Rail

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## THERMAL CHARACTERISTICS (Per Diode)

Rating	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	1.0	$^{\circ}C/W$

## ELECTRICAL CHARACTERISTICS (Per Diode)

Instantaneous Forward Voltage (Note 2) @ $I_F = 30$ Amps, $T_C = 25^{\circ}C$ @ $I_F = 30$ Amps, $T_C = 125^{\circ}C$ @ $I_F = 60$ Amps, $T_C = 25^{\circ}C$	$V_F$	0.62 0.55 0.75	Volts
Instantaneous Reverse Current (Note 2) @ Rated DC Voltage, $T_C = 25^{\circ}C$ @ Rated DC Voltage, $T_C = 100^{\circ}C$	$I_R$	1.0 50	mA

2. Pulse Test: Pulse Width = 300  $\mu s$ , Duty Cycle < 2.0%

## TYPICAL ELECTRICAL CHARACTERISTICS

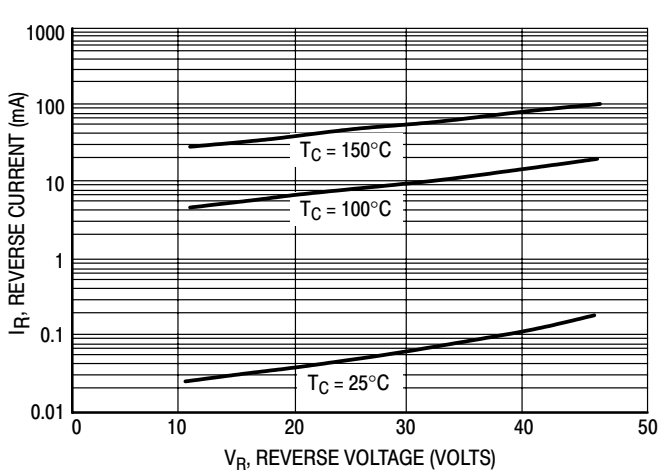


Figure 1. Typical Reverse Current

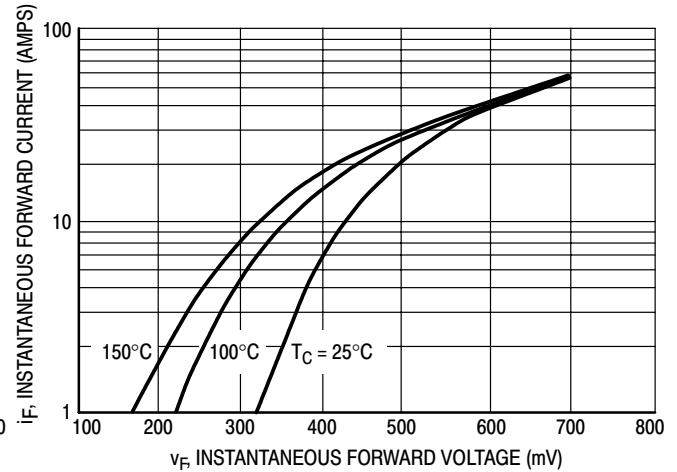
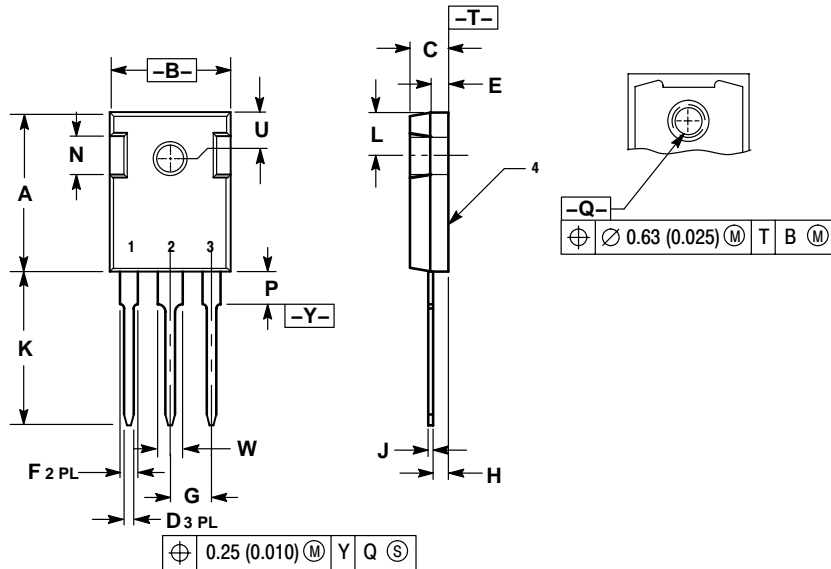


Figure 2. Typical Forward Voltage

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## PACKAGE DIMENSIONS

TO-247 PSI  
PLASTIC  
CASE 340L-02  
ISSUE D



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	20.32	21.08	0.800	0.830
B	15.75	16.26	0.620	0.640
C	4.70	5.30	0.185	0.209
D	1.00	1.40	0.040	0.055
E	2.20	2.60	0.087	0.102
F	1.65	2.13	0.065	0.084
G	5.45 BSC		0.215 BSC	
H	1.50	2.49	0.059	0.098
J	0.40	0.80	0.016	0.031
K	20.06	20.83	0.790	0.820
L	5.40	6.20	0.212	0.244
N	4.32	5.49	0.170	0.216
P	---	4.50	---	0.177
Q	3.55	3.65	0.140	0.144
U	6.15 BSC		0.242 BSC	
W	2.87	3.12	0.113	0.123

- STYLE 2:
- PIN 1. ANODE
  - CATHODE (S)
  - ANODE 2
  - CATHODES (S)

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